## APPLICATION DATA SHEET

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**Publication Filing Type:** 

new-utility

Application Type:

utility

Title of Invention:

FIN-BASED DOUBLE POLY DYNAMIC THRESHOLD CMOS FET WITH

SPACER GATE AND METHOD OF FABRICATION

**Customer Number Attorney:** 

30607

**Customer Number Correspondence Address:** 

30607

INVENTOR(s):

Primary Citizenship:

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Andres

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Residence State:

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